

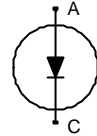
Fast switching diode chip in EMCON 3-Technology

FEATURES:

- 1700V EMCON 3 technology 200 μm chip
- soft, fast switching
- low reverse recovery charge
- small temperature coefficient

This chip is used for:

- EUPEC power modules



Applications:

- resonant applications, drives

Chip Type	V_R	I_F	Die Size	Package	Ordering Code
SIDC110D170H	1700V	200A	10.5 x 10.5 mm ²	sawn on foil	Q67050-A4179-A001

MECHANICAL PARAMETER:

Raster size	10.5 x 10.5	mm ²
Area total / active	110.25 / 90.9	
Anode pad size	8.48 x 8.48	
Thickness	200	μm
Wafer size	150	mm
Flat position	180	deg
Max. possible chips per wafer	122 pcs	
Passivation frontside	Photoimide	
Anode metallization	3200 nm Al Si Cu	
Cathode metallization	Ni Ag –system suitable for epoxy and soft solder die bonding	
Die bond	electrically conductive glue or solder	
Wire bond	Al, $\leq 500\mu\text{m}$	
Reject Ink Dot Size	\varnothing 0.65mm; max 1.2mm	
Recommended Storage Environment	store in original container, in dry nitrogen, < 6 month at an ambient temperature of 23°C	

Maximum Ratings

Parameter	Symbol	Condition	Value	Unit
Repetitive peak reverse voltage	V_{RRM}		1700	V
Continuous forward current limited by T_{jmax}	I_F		200	A
Single pulse forward current (depending on wire bond configuration)	I_{FSM}	$t_p = 10\text{ ms sinusoidal}$	930	
Maximum repetitive forward current limited by T_{jmax}	I_{FRM}		400	
Operating junction and storage temperature	T_j, T_{stg}		-55...+150	°C

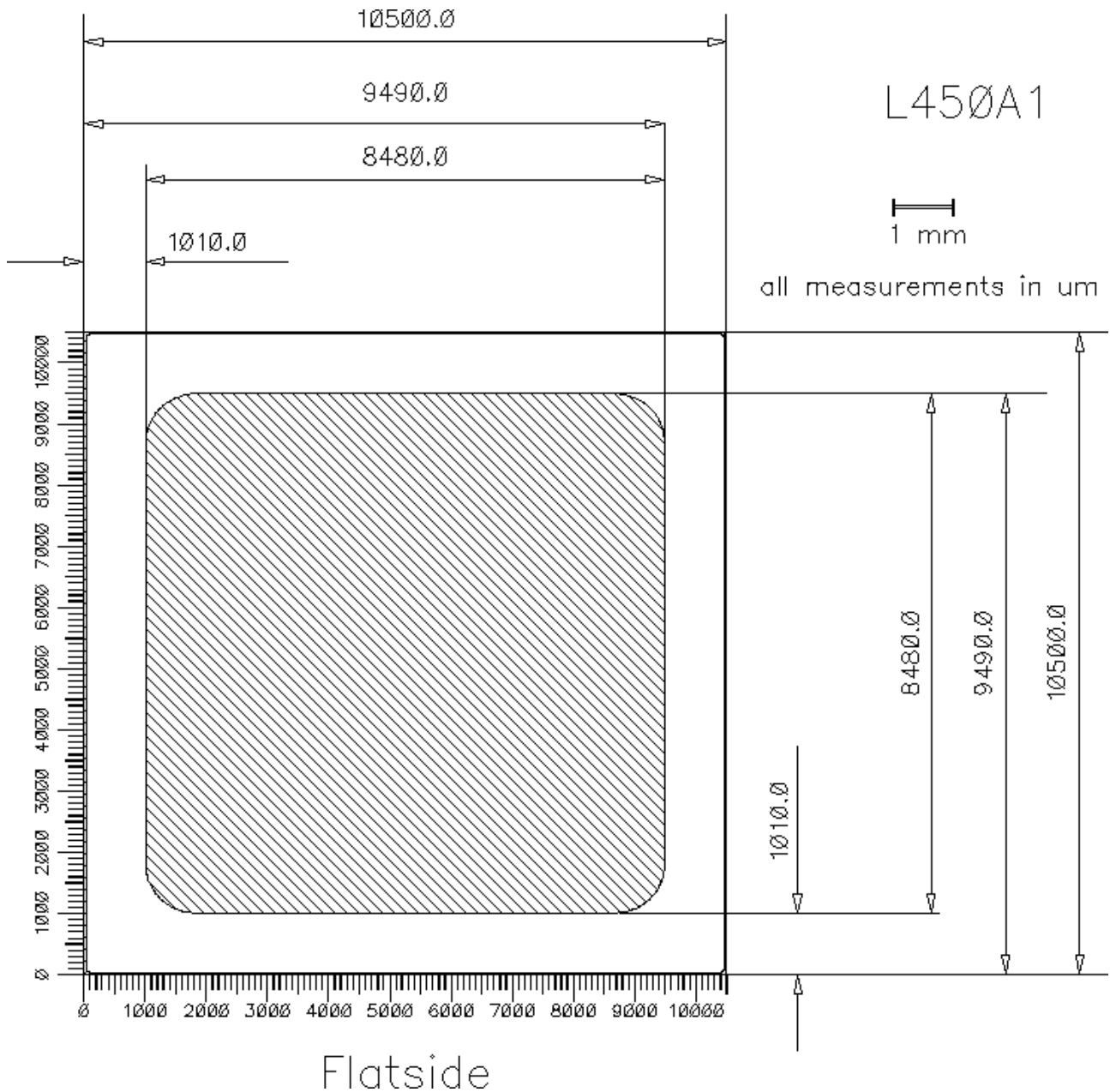
Static Electrical Characteristics (tested on chip), $T_j=25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions		Value			Unit
				min.	Typ.	max.	
Reverse leakage current	I_R	$V_R=1700\text{ V}$	$T_j=25\text{ °C}$			27	µA
Cathode-Anode breakdown Voltage	V_{Br}	$I_R=0.25\text{ mA}$	$T_j=25\text{ °C}$	1700			V
Forward voltage drop	V_F	$I_F=200\text{ A}$	$T_j=25\text{ °C}$		1.8		V

Dynamic Electrical Characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified, tested at component

Parameter	Symbol	Conditions		Value			Unit
				min.	Typ.	max.	
Peak recovery current	I_{RRM1}	$I_F=200\text{ A}$	$T_j = 25\text{ °C}$		171		A
	I_{RRM2}	$di/dt=960\text{ A/ms}$ $V_R=900\text{ V}$	$T_j = 125\text{ °C}$		204		
Reverse recovery charge	Q_{rr1}	$I_F=200\text{ A}$	$T_j=25\text{ °C}$		47.5		µC
	Q_{rr2}	$di/dt=960\text{ A/ms}$ $V_R=900\text{ V}$	$T_j=125\text{ °C}$		82.5		
Peak recovery energy	E_{rec1}	$I_F=200\text{ A}$	$T_j=25\text{ °C}$		32.5		mJ
	E_{rec2}	$di/dt=960\text{ A/ms}$ $V_R=900\text{ V}$	$T_j=125\text{ °C}$		57.5		

CHIP DRAWING:



FURTHER ELECTRICAL CHARACTERISTICS:

This chip data sheet refers to the device data sheet

INFINEON TECHNOLOGIES /
EUPEC

tbd

Description:

AQL 0,65 for visual inspection according to failure catalog

Electrostatic Discharge Sensitive Device according to MIL-STD 883

Test-Normen Villach/Prüffeld

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